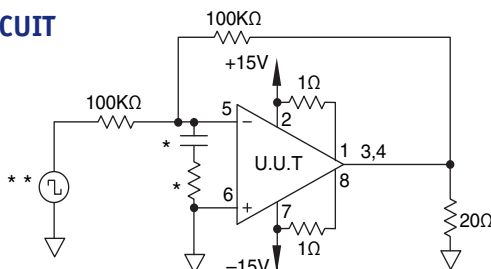


PA02M/883

SG	PARAMETER	SYMBOL	TEMP.	POWER	TEST CONDITIONS	MIN	MAX	UNITS
1	Quiescent current	I_o	25°C	±15V	$V_{IN} = 0, A_V = 100, R_{CL} = .2\Omega$		40	mA
1	Input offset voltage	V_{OS}	25°C	±15V	$V_{IN} = 0, A_V = 100$		10	mV
1	Input offset voltage	V_{OS}	25°C	±7V	$V_{IN} = 0, A_V = 100$		11.6	mV
1	Input offset voltage	V_{OS}	25°C	±19V	$V_{IN} = 0, A_V = 100$		10.8	mV
1	Input bias current, +IN	$+I_B$	25°C	±15V	$V_{IN} = 0$		200	pA
1	Input bias current, -IN	$-I_B$	25°C	±15V	$V_{IN} = 0$		200	pA
1	Input offset current	I_{OS}	25°C	±15V	$V_{IN} = 0$		100	pA
3	Quiescent current	I_o	-55°C	±15V	$V_{IN} = 0, A_V = 100, R_{CL} = .2\Omega$		60	mA
3	Input offset voltage	V_{OS}	-55°C	±15V	$V_{IN} = 0, A_V = 100$		14	mV
3	Input offset voltage	V_{OS}	-55°C	±7V	$V_{IN} = 0, A_V = 100$		15.6	mV
3	Input offset voltage	V_{OS}	-55°C	±19V	$V_{IN} = 0, A_V = 100$		14.8	mV
3	Input bias current, +IN	$+I_B$	-55°C	±15V	$V_{IN} = 0$		200	pA
3	Input bias current, -IN	$-I_B$	-55°C	±15V	$V_{IN} = 0$		200	pA
3	Input offset current	I_{OS}	-55°C	±15V	$V_{IN} = 0$		100	pA
2	Quiescent current	I_o	125°C	±15V	$V_{IN} = 0, A_V = 100, R_{CL} = .2\Omega$		60	mA
2	Input offset voltage	V_{OS}	125°C	±15V	$V_{IN} = 0, A_V = 100$		15	mV
2	Input offset voltage	V_{OS}	125°C	±7V	$V_{IN} = 0, A_V = 100$		16.6	mV
2	Input offset voltage	V_{OS}	125°C	±19V	$V_{IN} = 0, A_V = 100$		15.8	mV
2	Input bias current, +IN	$+I_B$	125°C	±15V	$V_{IN} = 0$		30	nA
2	Input bias current, -IN	$-I_B$	125°C	±15V	$V_{IN} = 0$		30	nA
2	Input offset current	I_{OS}	125°C	±15V	$V_{IN} = 0$		10	nA
4	Output voltage, $I_o = 5A$	V_o	25°C	±9V	$R_L = 1\Omega, R_{CL} = 0\Omega$	5		V
4	Output voltage, $I_o = 36mA$	V_o	25°C	±19V	$R_L = 500\Omega$	18		V
4	Output voltage, $I_o = 2A$	V_o	25°C	±12V	$R_L = 5\Omega, R_{CL} = 0\Omega$	10		V
4	Current limits	I_{CL}	25°C	±9V	$R_L = 5\Omega, R_{CL} = 1\Omega$.54	.86	A
4	Stability/noise	E_N	25°C	±15V	$R_L = 500\Omega, A_V = 1, C_L = 1.5nF$		1	mV
4	Slew rate	SR	25°C	±18V	$R_L = 500\Omega$	13	100	V/μs
4	Open loop gain	A_{OL}	25°C	±15V	$R_L = 500\Omega, F = 10Hz$	86		dB
4	Common mode rejection	CMR	25°C	±8.25V	$R_L = 500\Omega, F = DC, V_{CM} = \pm 2.25V$	70		dB
6	Output voltage, $I_o = 5A$	V_o	-55°C	±9V	$R_L = 1\Omega, R_{CL} = 0\Omega$	5		V
6	Output voltage, $I_o = 36mA$	V_o	-55°C	±19V	$R_L = 500\Omega$	18		V
6	Output voltage, $I_o = 2A$	V_o	-55°C	±12V	$R_L = 5\Omega, R_{CL} = 0\Omega$	10		V
6	Stability/noise	E_N	-55°C	±15V	$R_L = 500\Omega, A_V = 1, C_L = 1.5nF$		1	mV
6	Slew rate	SR	-55°C	±18V	$R_L = 500\Omega$	13	100	V/μs
6	Open loop gain	A_{OL}	-55°C	±15V	$R_L = 500\Omega, F = 10Hz$	86		dB
6	Common mode rejection	CMR	-55°C	±8.25V	$R_L = 500\Omega, F = DC, V_{CM} = \pm 2.25V$	70		dB
5	Output voltage, $I_o = 3A$	V_o	125°C	±7V	$R_L = 1\Omega, R_{CL} = 0\Omega$	3		V
5	Output voltage, $I_o = 36mA$	V_o	125°C	±19V	$R_L = 500\Omega$	18		V
5	Output voltage, $I_o = 2A$	V_o	125°C	±12V	$R_L = 5\Omega, R_{CL} = 0\Omega$	10		V
5	Stability/noise	E_N	125°C	±15V	$R_L = 500\Omega, A_V = 1, C_L = 1.5nF$		1	mV
5	Slew rate	SR	125°C	±18V	$R_L = 500\Omega$	8.5	100	V/μs
5	Open loop gain	A_{OL}	125°C	±15V	$R_L = 500\Omega, F = 10Hz$	86		dB
5	Common mode rejection	CMR	125°C	±8.25V	$R_L = 500\Omega, F = DC, V_{CM} = \pm 2.25V$	70		dB

BURN IN CIRCUIT



* These components are used to stabilize device due to poor high frequency characteristics of burn in board.

** Input signals are calculated to result in internal power dissipation of approximately 2.1W at case temperature = 125°C.